

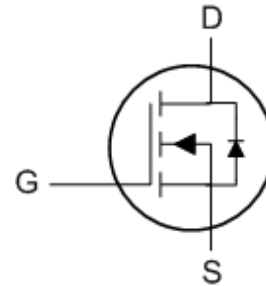


- ★ Super Low Gate Charge
- ★ 100% EAS Guaranteed
- ★ Green Device Available
- ★ Excellent CdV/dt effect decline
- ★ Advanced high cell density Trench technology

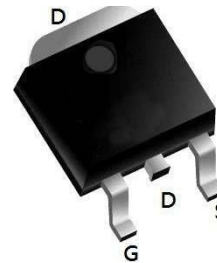
### Description

The WLU120N03 is the high cell density trenched N-ch MOSFETs, which provide excellent R<sub>DS(on)</sub> and gate charge for most of the synchronous buck converter applications.

The WLU120N03 meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.



### TO252 Pin Configuration



### Product Summary

BVDSS	R <sub>DS(on)</sub>	I <sub>D</sub>
30V	3.0mΩ	120 A

### Absolute Maximum Ratings

Symbol	Parameter	Rating		Units
		10s	Steady State	
V <sub>DS</sub>	Drain-Source Voltage	30		V
V <sub>GS</sub>	Gate-Source Voltage	±20		V
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	120		A
I <sub>D</sub> @T <sub>C</sub> =100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	75		A
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup>	384		A
EAS	Single Pulse Avalanche Energy <sup>3</sup>	198		mJ
I <sub>AS</sub>	Avalanche Current	53.8		A
P <sub>D</sub> @T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup>	62.5		W
P <sub>D</sub> @T <sub>A</sub> =25°C	Total Power Dissipation <sup>4</sup>	6	2.42	W
T <sub>STG</sub>	Storage Temperature Range	-55 to 175		°C
T <sub>J</sub>	Operating Junction Temperature Range	-55 to 175		°C

### Thermal Data

Symbol	Parameter	Typ.	Max.	Unit
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient <sup>1</sup>	---	62	°C/W
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient <sup>1</sup> (t ≤ 10s)	---	25	°C/W
R <sub>θJC</sub>	Thermal Resistance Junction-Case <sup>1</sup>	---	2.4	°C/W



### Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>DS</sub> =250μA	30	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =24V, V <sub>GS</sub> =0V T <sub>J</sub> =85°C	-	-	1 30	μA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>DS</sub> =250μA	1.4	1.7	2.5	V
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
R <sub>DS(ON)</sub> <sup>d</sup>	Drain-Source On-state Resistance	V <sub>GS</sub> =10V, I <sub>DS</sub> =20A T <sub>J</sub> =125°C	-	3.0 4.4	3.8 -	mΩ
		V <sub>GS</sub> =4.5V, I <sub>DS</sub> =15A	-	4.0	5.5	
Gfs	Forward Transconductance	V <sub>DS</sub> =5V, I <sub>DS</sub> =10A	-	24.6	-	S
<b>Diode Characteristics</b>						
V <sub>SD</sub> <sup>d</sup>	Diode Forward Voltage	I <sub>SD</sub> =20A, V <sub>GS</sub> =0V	-	0.8	1.1	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>DS</sub> =20A, di <sub>SD</sub> /dt=100A/μs	-	35.6	-	ns
t <sub>a</sub>	Charge Time		-	19.3	-	
t <sub>b</sub>	Discharge Time		-	16.3	-	
Q <sub>rr</sub>	Reverse Recovery Charge		-	26	-	
<b>Dynamic Characteristics</b> <sup>e</sup>						
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> =0V, V <sub>DS</sub> =0V, F=1MHz	-	1	2	Ω
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =15V, Frequency=1.0MHz	-	2485	2971	pF
C <sub>oss</sub>	Output Capacitance		-	850	-	
C <sub>rss</sub>	Reverse Transfer Capacitance		-	85	-	
t <sub>d(ON)</sub>	Turn-on Delay Time	V <sub>DD</sub> =15V, R <sub>L</sub> =15Ω, I <sub>DS</sub> =1A, V <sub>GEN</sub> =10V, R <sub>G</sub> =6Ω	-	12.4	23	ns
t <sub>r</sub>	Turn-on Rise Time		-	9.5	18	
t <sub>d(OFF)</sub>	Turn-off Delay Time		-	27.2	49	
t <sub>f</sub>	Turn-off Fall Time		-	35.2	64	
<b>Gate Charge Characteristics</b> <sup>e</sup>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =15V, V <sub>GS</sub> =10V, I <sub>DS</sub> =20A	-	20.6	28.8	nC
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =15V, V <sub>GS</sub> =4.5V, I <sub>DS</sub> =20A	-	9.8	-	
Q <sub>gth</sub>	Threshold Gate Charge		-	1.8	-	
Q <sub>gs</sub>	Gate-Source Charge		-	3.8	-	
Q <sub>gd</sub>	Gate-Drain Charge		-	3.7	-	

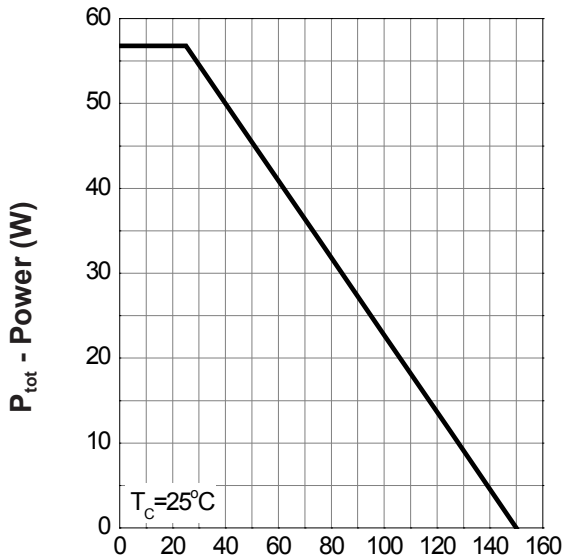
Note d : Pulse test ; pulse width≤300μs, duty cycle≤2%.

Note e : Guaranteed by design, not subject to production testing.



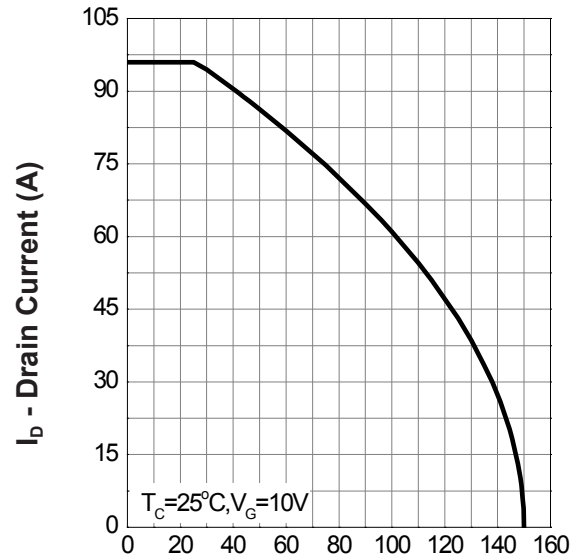
### Typical Operating Characteristics

Power Dissipation



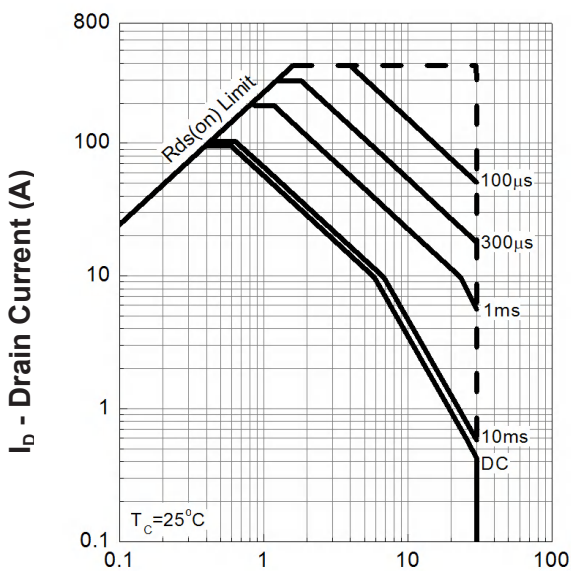
$T_j$  - Junction Temperature (°C)

Drain Current



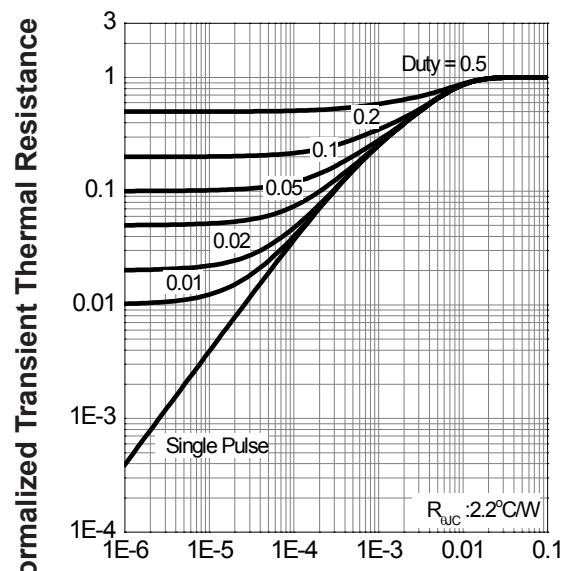
$T_j$  - Junction Temperature (°C)

Safe Operation Area



$V_{DS}$  - Drain - Source Voltage (V)

Thermal Transient Impedance

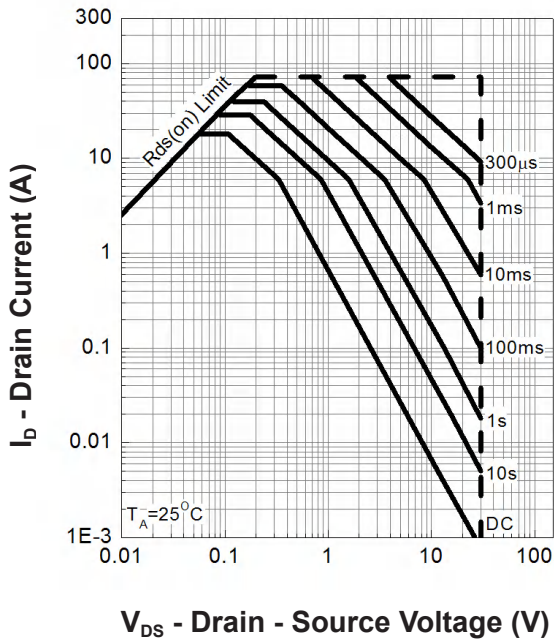


Square Wave Pulse Duration (sec)

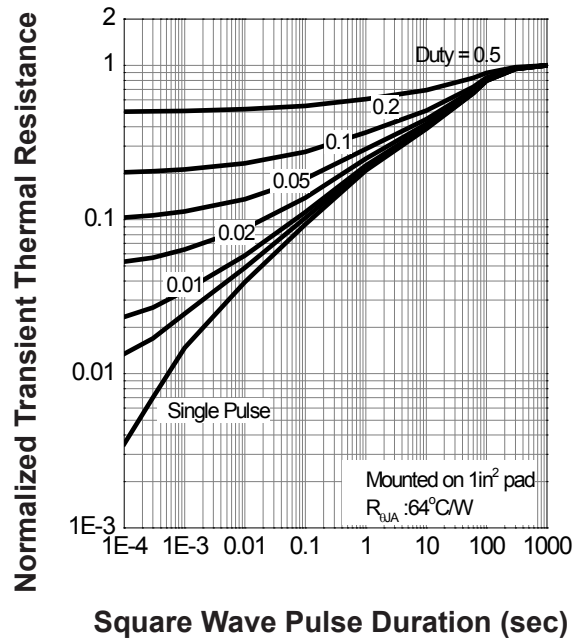


### Typical Operating Characteristics(Cont.)

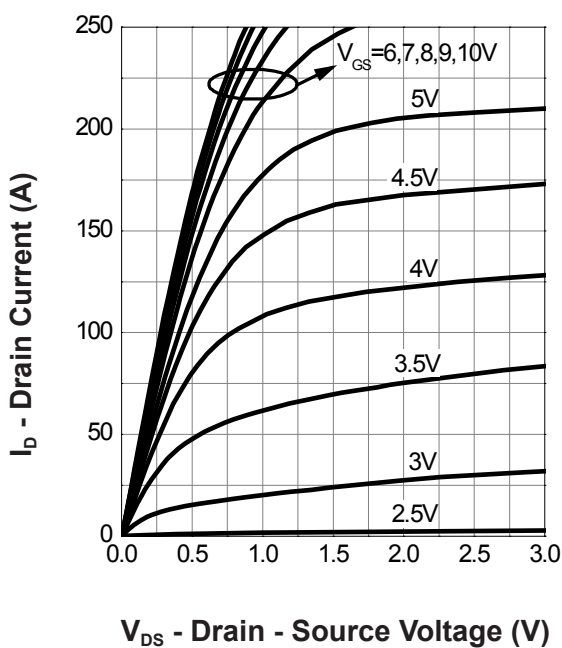
#### Safe Operation Area



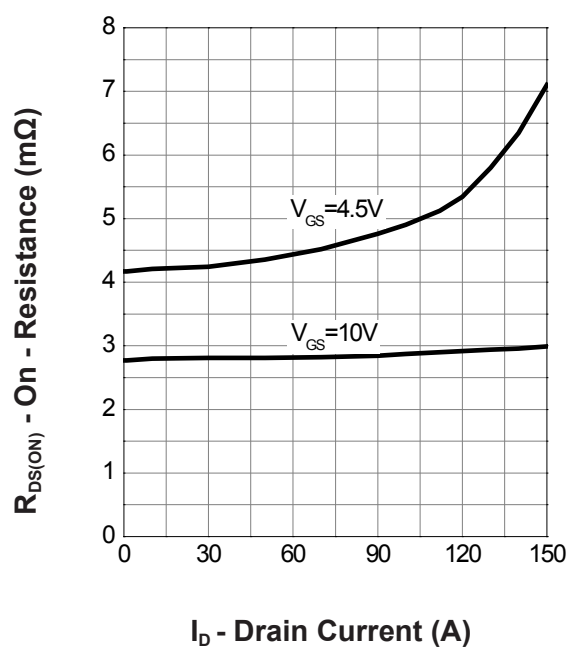
#### Thermal Transient Impedance



#### Output Characteristics



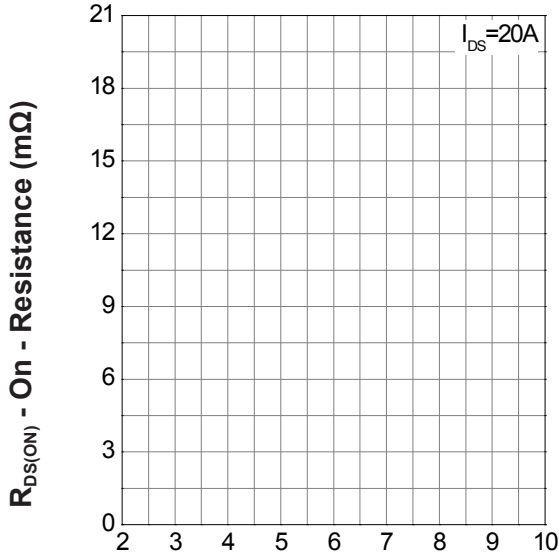
#### Drain-Source On Resistance





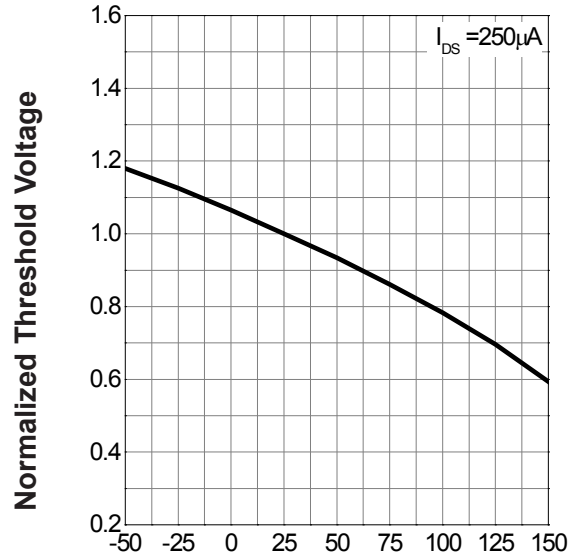
### Typical Operating Characteristics(Cont.)

Gate-Source On Resistance



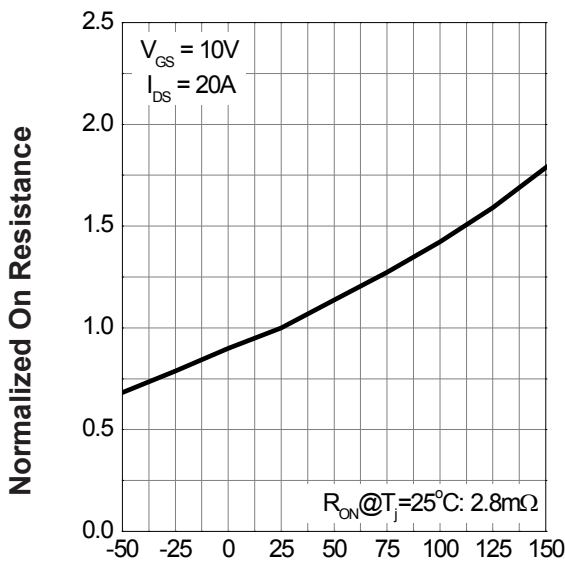
V<sub>GS</sub> - Gate - Source Voltage (V)

Gate Threshold Voltage



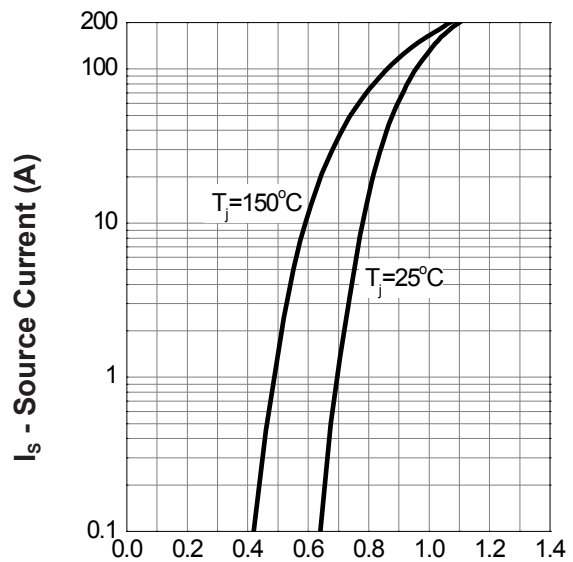
T<sub>J</sub> - Junction Temperature (°C)

Drain-Source On Resistance



T<sub>J</sub> - Junction Temperature (°C)

Source-Drain Diode Forward

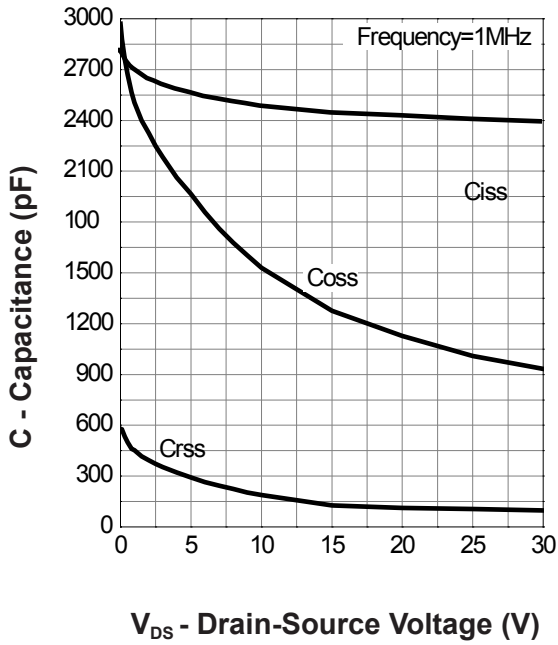


V<sub>SD</sub> - Source - Drain Voltage (V)

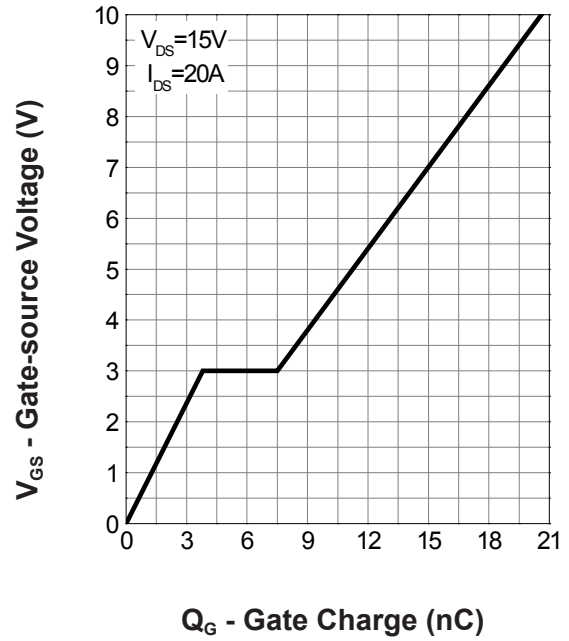


### Typical Operating Characteristics(Cont.)

Capacitance

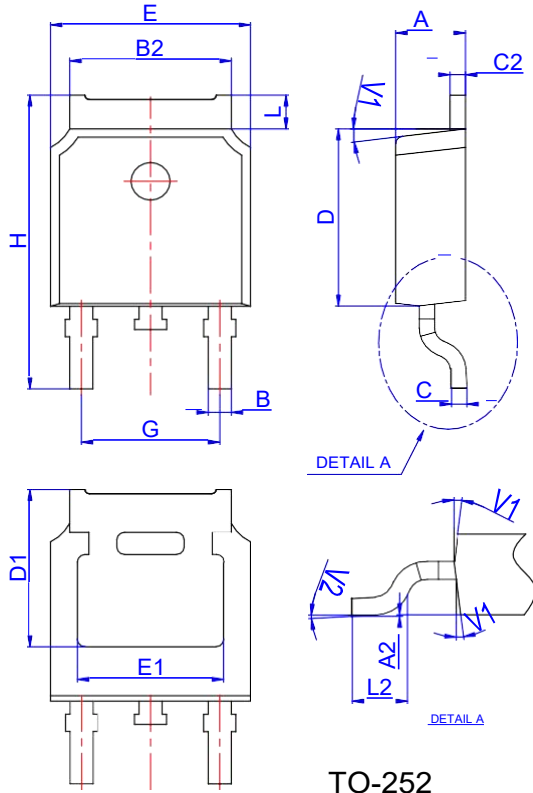


Gate Charge



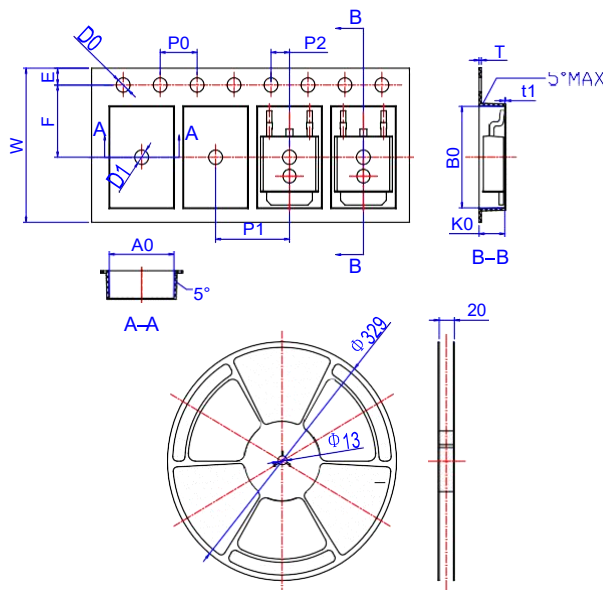


Package Mechanical Data TO 252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Reel Specification-TO-252-4R



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
T	0.24		0.27	0.009		0.011
t1	0.10			0.004		
10P0	39.80	40.00	40.20	1.567	1.575	1.583



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